- State-of-the-Art BiCMOS Design Significantly Reduces I_{CCZ}
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Designed to Facilitate Incident-Wave Switching for Line Impedances of 25 Ω or Greater
- Distributed V_{CC} and GND Pins Minimize Noise Generated by the Simultaneous Switching of Outputs
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic and Ceramic 300-mil DIPs (JT, NT)

description

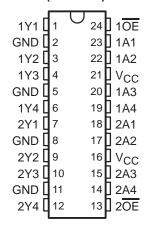
These $25-\Omega$ octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

These buffers are capable of sinking 188-mA I_{OL} , which facilitates switching 25- Ω transmission lines on the incident wave. The distributed V_{CC} and GND pins minimize switching noise for more reliable system operation.

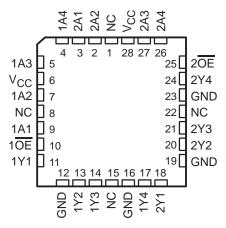
When the output-enable (1 \overline{OE} and 2 \overline{OE}) inputs are low, the device transmits data from the A inputs to the Y outputs. When 1 \overline{OE} and 2 \overline{OE} are high, the outputs are in the high-impedance state.

The SN54BCT25244 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74BCT25244 is characterized for operation from 0°C to 70°C.

SN54BCT25244 . . . JT OR W PACKAGE SN74BCT25244 . . . DW OR NT PACKAGE (TOP VIEW)



SN54BCT25244 . . . FK PACKAGE (TOP VIEW)



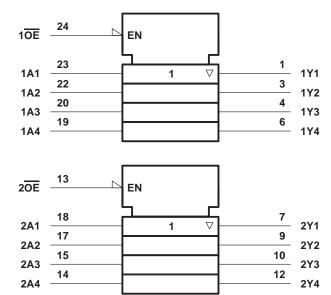
NC - No internal connection

FUNCTION TABLE (each buffer/driver)

INP	JTS	OUTPUT
OE	Α	Υ
L	Н	Н
L	L	L
Н	Χ	Z

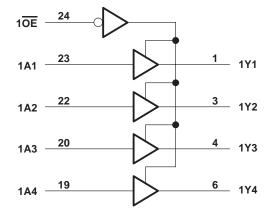


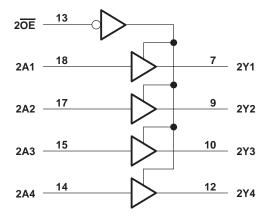
logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





Pin numbers shown are for the DW, JT, NT, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the disabled or power-off state, VO	
Voltage range applied to any output in the high state, VO	0.5 V to V _{CC}
Input clamp current, I _{IK} (V _I < 0)	–30 mA
Current into any output in the low state, IO: SN54BCT25244	250 mA
SN74BCT25244	376 mA
Operating free-air temperature range: SN54BCT25244	−55°C to 125°C
SN74BCT25244	0°C to 70°C
Storage temperature range	65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions (see Note 2)

		SN54BCT25244			SN74BCT25244			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
V _{IL}	Low-level input voltage			0.8			0.8	V
liK	Input clamp current			-18			-18	mA
ІОН	High-level output current			-53			-80	mA
loL	Low-level output current			125			188	mA
TA	Operating free-air temperature	-55		125	0		70	°C

NOTE 2: Unused or floating inputs must be held high or low.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		SN54BCT25244			SN74BCT25244			UNIT	
PARAMETER			MIN	TYP†	MAX	MIN	TYP	MAX	UNII	
VIK	V _{CC} = 4.5 V,	I _I = -18 mA			-1.2			-1.2	V	
	$V_{CC} = 4.75 V$,	$I_{OH} = -3 \text{ mA}$				2.7				
Vон	V _{CC} = 4.5 V	$I_{OH} = -53 \text{ mA}$	2						V	
	vCC = 4.5 v	$I_{OH} = -80 \text{ mA}$				2				
		I _{OL} = 94 mA		0.38	0.55		0.42	0.55		
V_{OL}	V _{CC} = 4.5 V	I _{OL} = 125 mA			0.8				V	
		I _{OL} = 188 mA						0.7		
lį	V _{CC} = 5.5 V,	V _I = 5.5 V			0.1			0.1	mA	
lіН	V _{CC} = 5.5 V,	V _I = 2.7 V			20			20	μΑ	
I _{IL}	$V_{CC} = 5.5 \text{ V},$	V _I = 0.5 V			-0.6			-0.6	mA	
lozh	V _{CC} = 5.5 V,	V _O = 2.7 V			50			50	μΑ	
lozL	V _{CC} = 5.5 V,	V _O = 0.5 V			-50			-50	μΑ	
ICCL	V _{CC} = 5.5 V,	Outputs open		90	119		90	119	mA	
Іссн	V _{CC} = 5.5 V,	Outputs open		59	78		59	78	mA	
ICCZ	V _{CC} = 5.5 V,	Outputs open		7	11		7	11	mA	
C _i	V _{CC} = 5 V,	V _I = 2.5 V or 0.5 V		5.5			5.5		pF	
Co	V _{CC} = 5 V,	V _O = 2.5 V or 0.5 V		17			17		pF	

 $^{^{\}dagger}$ All typical values are at VCC = 5 V, TA = 25°C.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Note 3)

	• •		, ,		•					
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			SN54BCT25244		SN74BCT25244		UNIT
	(INPOT)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	А	Y	1	3.2	4.9	1	5.6	1	5.5	ns
t _{PHL}			2	4	5.6	2	6.3	2	6	
^t PZH	OE	Y	3.2	5.6	8.5	3.2	9.7	3.2	9.3	ns
t _{PZL}			3.7	6.3	9.2	3.7	10.4	3.7	10.2	
^t PHZ	ŌĒ	V	1.6	3.6	5.5	1.6	6.5	1.6	6.3	
tPLZ		·	3.1	5.3	7.8	3.1	9.5	3.1	8.4	ns

NOTE 3: Load circuits and voltage waveforms are shown in Section 1.



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